

Welcome to E-XFL.COM

#### What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

#### Details

Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	4MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	12
Program Memory Size	768B (512 x 12)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	25 x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 6.25V
Data Converters	-
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	18-SOIC (0.295", 7.50mm Width)
Supplier Device Package	18-SOIC
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16c54t-rci-so

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

#### 3.1 **Clocking Scheme/Instruction** Cycle

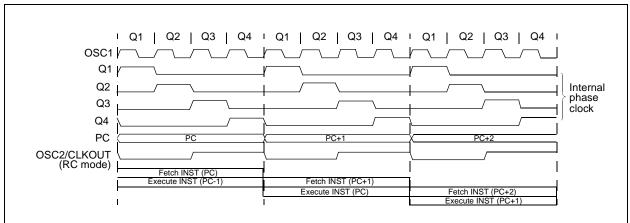
The clock input (OSC1/CLKIN pin) is internally divided by four to generate four non-overlapping quadrature clocks, namely Q1, Q2, Q3 and Q4. Internally, the program counter is incremented every Q1 and the instruction is fetched from program memory and latched into the instruction register in Q4. It is decoded and executed during the following Q1 through Q4. The clocks and instruction execution flow are shown in Figure 3-2 and Example 3-1.

#### 3.2 Instruction Flow/Pipelining

An Instruction Cycle consists of four Q cycles (Q1, Q2, Q3 and Q4). The instruction fetch and execute are pipelined such that fetch takes one instruction cycle, while decode and execute takes another instruction cycle. However, due to the pipelining, each instruction effectively executes in one cycle. If an instruction causes the program counter to change (e.g., GOTO), then two cycles are required to complete the instruction (Example 3-1).

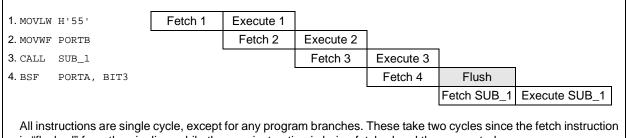
A fetch cycle begins with the program counter (PC) incrementing in Q1.

In the execution cycle, the fetched instruction is latched into the Instruction Register in cycle Q1. This instruction is then decoded and executed during the Q2, Q3 and Q4 cycles. Data memory is read during Q2 (operand read) and written during Q4 (destination write).



#### FIGURE 3-2: **CLOCK/INSTRUCTION CYCLE**

#### EXAMPLE 3-1: INSTRUCTION PIPELINE FLOW



is "flushed" from the pipeline, while the new instruction is being fetched and then executed.

# 7.6 I/O Programming Considerations

### 7.6.1 BI-DIRECTIONAL I/O PORTS

Some instructions operate internally as read followed by write operations. The BCF and BSF instructions, for example, read the entire port into the CPU, execute the bit operation and re-write the result. Caution must be used when these instructions are applied to a port where one or more pins are used as input/outputs. For example, a BSF operation on bit5 of PORTB will cause all eight bits of PORTB to be read into the CPU, bit5 to be set and the PORTB value to be written to the output latches. If another bit of PORTB is used as a bi-directional I/O pin (say bit0) and it is defined as an input at this time, the input signal present on the pin itself would be read into the CPU and rewritten to the data latch of this particular pin, overwriting the previous content. As long as the pin stays in the Input mode, no problem occurs. However, if bit0 is switched into Output mode later on, the content of the data latch may now be unknown.

Example 7-1 shows the effect of two sequential read-modify-write instructions (e.g., BCF, BSF, etc.) on an I/O port.

A pin actively outputting a high or a low should not be driven from external devices at the same time in order to change the level on this pin ("wired-or", "wired-and"). The resulting high output currents may damage the chip.

### EXAMPLE 7-1: READ-MODIFY-WRITE INSTRUCTIONS ON AN I/O PORT

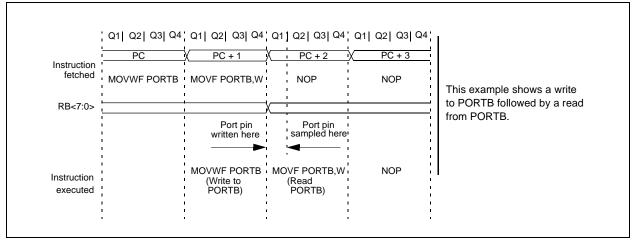
;Initial PORT Settings
; PORTB<7:4> Inputs
; PORTB<3:0> Outputs
;PORTB<7:6> have external pull-ups and are
;not connected to other circuitry
;

;				PORT	latch	PORT	pins
;							
	BCF	PORTB,	7	;01pp	pppp	11pp	pppp
	BCF	PORTB,	6	;10pp	pppp	11pp	pppp
	MOVLW	H'3F'		;			
	TRIS	PORTB		;10pp	pppp	10pp	pppp
;							

;Note that the user may have expected the pin ;values to be 00pp pppp. The 2nd BCF caused ;RB7 to be latched as the pin value (High).

# 7.6.2 SUCCESSIVE OPERATIONS ON I/O PORTS

The actual write to an I/O port happens at the end of an instruction cycle, whereas for reading, the data must be valid at the beginning of the instruction cycle (Figure 7-2). Therefore, care must be exercised if a write followed by a read operation is carried out on the same I/O port. The sequence of instructions should allow the pin voltage to stabilize (load dependent) before the next instruction, which causes that file to be read into the CPU, is executed. Otherwise, the previous state of that pin may be read into the CPU rather than the new state. When in doubt, it is better to separate these instructions with a NOP or another instruction not accessing this I/O port.



# FIGURE 7-2: SUCCESSIVE I/O OPERATION

# 8.1 Using Timer0 with an External Clock

When an external clock input is used for Timer0, it must meet certain requirements. The external clock requirement is due to internal phase clock (Tosc) synchronization. Also, there is a delay in the actual incrementing of Timer0 after synchronization.

## 8.1.1 EXTERNAL CLOCK SYNCHRONIZATION

When no prescaler is used, the external clock input is the same as the prescaler output. The synchronization of T0CKI with the internal phase clocks is accomplished by sampling the prescaler output on the Q2 and Q4 cycles of the internal phase clocks (Figure 8-5). Therefore, it is necessary for T0CKI to be high for at least 2Tosc (and a small RC delay of 20 ns) and low for at least 2Tosc (and a small RC delay of 20 ns). Refer to the electrical specification of the desired device. When a prescaler is used, the external clock input is divided by the asynchronous ripple counter-type prescaler so that the prescaler output is symmetrical. For the external clock to meet the sampling requirement, the ripple counter must be taken into account. Therefore, it is necessary for TOCKI to have a period of at least 4Tosc (and a small RC delay of 40 ns) divided by the prescaler value. The only requirement on TOCKI high and low time is that they do not violate the minimum pulse width requirement of 10 ns. Refer to parameters 40, 41 and 42 in the electrical specification of the desired device.

# 8.1.2 TIMER0 INCREMENT DELAY

Since the prescaler output is synchronized with the internal clocks, there is a small delay from the time the external clock edge occurs to the time the Timer0 module is actually incremented. Figure 8-5 shows the delay from the external clock edge to the timer incrementing.



Belay from clock input change to Timer0 increment is 3 lose to 7 lose (duration of Q = lose). There the error in measuring the interval between two edges on Timer0 input = ± 4 Tose max.

# 8.2 Prescaler

An 8-bit counter is available as a prescaler for the Timer0 module, or as a postscaler for the Watchdog Timer (WDT), respectively (Section 9.2.1). For simplicity, this counter is being referred to as "prescaler" throughout this data sheet. Note that the prescaler may be used by either the Timer0 module or the WDT, but not both. Thus, a prescaler assignment for the Timer0 module means that there is no prescaler for the WDT, and vice-versa.

The PSA and PS<2:0> bits (OPTION<3:0>) determine prescaler assignment and prescale ratio.

When assigned to the Timer0 module, all instructions writing to the TMR0 register (e.g., CLRF 1, MOVWF 1, BSF 1, x, etc.) will clear the prescaler. When assigned to WDT, a CLRWDT instruction will clear the prescaler along with the WDT. The prescaler is neither readable nor writable. On a RESET, the prescaler contains all '0's.

#### 8.2.1 SWITCHING PRESCALER ASSIGNMENT

The prescaler assignment is fully under software control (i.e., it can be changed "on the fly" during program execution). To avoid an unintended device RESET, the following instruction sequence (Example 8-1) must be executed when changing the prescaler assignment from Timer0 to the WDT.

### EXAMPLE 8-1: CHANGING PRESCALER (TIMER0→WDT)

CLRWDT	;Clear WDT
CLRF TMR0	Clear TMR0 & Prescaler
MOVLW B'00xx1111'	;Last 3 instructions in
	this example
OPTION	;are required only if
	;desired
CLRWDT	;PS<2:0> are 000 or
	;001
MOVLW B'00xx1xxx'	;Set Prescaler to
OPTION	;desired WDT rate

To change prescaler from the WDT to the Timer0 module, use the sequence shown in Example 8-2. This sequence must be used even if the WDT is disabled. A CLRWDT instruction should be executed before switching the prescaler.

# EXAMPLE 8-2: CHANGING PRESCALER (WDT $\rightarrow$ TIMER0)

CLRWDT		;Clear WDT and
		;prescaler
MOVLW	B'xxxx0xxx'	;Select TMR0, new
		;prescale value and
		;clock source

OPTION





NOTES:

# 12.3 DC Characteristics: PIC16C54/55/56/57-RCE, XTE, 10E, HSE, LPE (Extended)

	PIC16C54/55/56/57-RCE, XTE, 10E, HSE, LPE (Extended)		Standard Operating Conditions (unless otherwise specified Operating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended					
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions	
D001	Vdd	Supply Voltage PIC16C5X-RCE PIC16C5X-XTE PIC16C5X-10E PIC16C5X-HSE PIC16C5X-LPE	3.25 3.25 4.5 4.5 2.5		6.0 6.0 5.5 5.5 6.0	V V V V		
D002	Vdr	RAM Data Retention Voltage <sup>(1)</sup>	—	1.5*	—	V	Device in SLEEP mode	
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset	
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*		_	V/ms	See Section 5.1 for details on Power-on Reset	
D010	IDD	Supply Current <sup>(2)</sup> PIC16C5X-RCE <sup>(3)</sup> PIC16C5X-XTE PIC16C5X-10E PIC16C5X-HSE PIC16C5X-HSE PIC16C5X-LPE		1.8 1.8 4.8 4.8 9.0 19	3.3 3.3 10 10 20 55	mA mA mA mA μA	Fosc = 4 MHz, VDD = $5.5V$ Fosc = 4 MHz, VDD = $5.5V$ Fosc = 10 MHz, VDD = $5.5V$ Fosc = 10 MHz, VDD = $5.5V$ Fosc = 16 MHz, VDD = $5.5V$ Fosc = $32$ kHz, VDD = $3.25V$ , WDT disabled	
D020	IPD	Power-down Current <sup>(2)</sup>	—	5.0 0.8	22 18	μΑ μΑ	VDD = 3.25V, WDT enabled VDD = 3.25V, WDT disabled	

\* These parameters are characterized but not tested.

† Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

**Note 1:** This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

- a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
- b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
- **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k $\Omega$ .

		Standard Operating Conditions (unless otherwise specified)							
AC Characteristics		Operating Temperature $0^{\circ}C \leq TA \leq +70^{\circ}C$ for commercial $-40^{\circ}C \leq TA \leq +85^{\circ}C$ for industrial							
				TA ≤ +125					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions		
1	Tosc	External CLKIN Period <sup>(1)</sup>	250	—	_	ns	XT OSC mode		
			100	—	—	ns	10 MHz mode		
			50	—	—	ns	HS osc mode (Comm/Ind)		
			62.5	—	—	ns	HS osc mode (Ext)		
			25	—	_	μS	LP OSC mode		
		Oscillator Period <sup>(1)</sup>	250	—	—	ns	RC OSC mode		
			250	—	10,000	ns	XT OSC mode		
			100	—	250	ns	10 MHz mode		
			50	—	250	ns	HS OSC mode (Comm/Ind)		
			62.5	—	250	ns	HS osc mode (Ext)		
			25	—	_	μS	LP OSC mode		
2	Тсу	Instruction Cycle Time <sup>(2)</sup>	—	4/Fosc		—			
3	TosL,	Clock in (OSC1) Low or High	85*	—	—	ns	XT oscillator		
	TosH	Time	20*	—	—	ns	HS oscillator		
			2.0*	—		μS	LP oscillator		
4	TosR,	Clock in (OSC1) Rise or Fall	—	—	25*	ns	XT oscillator		
	TosF	Time	—	—	25*	ns	HS oscillator		
			—	—	50*	ns	LP oscillator		

#### TABLE 12-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54/55/56/57

\* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

**Note 1:** All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

2: Instruction cycle period (TCY) equals four times the input oscillator time base period.

© 1997-2013 Microchip Technology Inc.

#### 13.4 DC Characteristics: PIC16CR54A-04E, 10E, 20E (Extended)

DC CH	ARACTER	RISTICS	Standard Operating Conditions (unless otherwise specified)Operating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended					
Param No.	Symbol	Characteristic	Min	Тур†	Мах	Units	Conditions	
D030	VIL	Input Low Voltage						
		I/O ports	Vss		0.15 Vdd	V	Pin at hi-impedance	
		MCLR (Schmitt Trigger)	Vss		0.15 VDD	V		
		T0CKI (Schmitt Trigger)	Vss		0.15 VDD	V		
		OSC1 (Schmitt Trigger)	Vss		0.15 VDD	V	RC mode only <sup>(3)</sup>	
		OSC1	Vss	—	0.3 Vdd	V	XT, HS and LP modes	
D040	Vін	Input High Voltage						
		I/O ports	0.45 Vdd		Vdd	V	For all VDD <sup>(4)</sup>	
		I/O ports	2.0		Vdd	V	$4.0V < VDD \le 5.5V^{(4)}$	
		I/O ports	0.36 Vdd		Vdd	V	VDD > 5.5V	
		MCLR (Schmitt Trigger)	0.85 VDD		Vdd	V		
		T0CKI (Schmitt Trigger)	0.85 VDD		Vdd	V		
		OSC1 (Schmitt Trigger)	0.85 VDD		Vdd	V	RC mode only <sup>(3)</sup>	
		OSC1	0.7 Vdd	—	Vdd	V	XT, HS and LP modes	
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 Vdd*	—	_	V		
D060	lı∟	Input Leakage Current <sup>(1,2)</sup>					<b>For</b> VDD ≤ <b>5.5</b> V:	
		I/O ports	-1.0	0.5	+1.0	μA	$VSS \leq VPIN \leq VDD$ ,	
							pin at hi-impedance	
		MCLR	-5.0		_	μA	VPIN = VSS + 0.25V	
		MCLR	_	0.5	+5.0	μΑ	VPIN = VDD	
		TOCKI	-3.0	0.5	+3.0	μΑ	$VSS \leq VPIN \leq VDD$	
		OSC1	-3.0	0.5	+3.0	μA	$VSS \leq VPIN \leq VDD$ ,	
							XT, HS and LP modes	
D080	Vol	Output Low Voltage						
		I/O ports	I —	—	0.6	V	IOL = 8.7 mA, VDD = 4.5V	
		OSC2/CLKOUT			0.6	V	IOL = 1.6  mA, VDD = 4.5 V,	
							RC mode only	
D090	Voh	Output High Voltage <sup>(2)</sup>						
		I/O ports	Vdd - 0.7	—	—	V	IOH = −5.4 mA, VDD = 4.5\	
		OSC2/CLKOUT	Vdd - 0.7	—	-	V	IOH = -1.0  mA,  VDD = 4.5  V RC mode only	

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

**2:** Negative current is defined as coming out of the pin.

3: For the RC mode, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.

4: The user may use the better of the two specifications.



## FIGURE 13-4: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16CR54A

## TABLE 13-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16CR54A

AC Chara	cteristics						
Param No.	Symbol	Characteristic Min Typ† Max Units Conditions			Conditions		
30	TmcL	MCLR Pulse Width (low)	1.0*			μS	VDD = 5.0V
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	7.0*	18*	40*	ms	VDD = 5.0V (Comm)
32	Tdrt	Device Reset Timer Period	7.0*	18*	30*	ms	VDD = 5.0V (Comm)
34	Tioz	I/O Hi-impedance from MCLR Low	_	_	1.0*	μS	

These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

TABLE 15-1:	EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54A
-------------	--

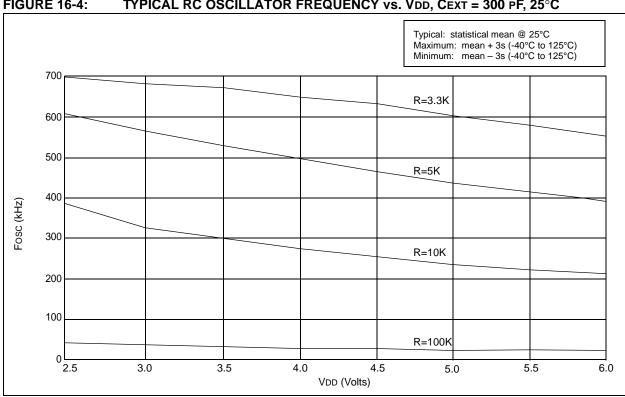
AC Chara	acteristics	$\begin{array}{llllllllllllllllllllllllllllllllllll$						
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
1	Tosc	External CLKIN Period <sup>(1)</sup>	250	_		ns	XT OSC mode	
			500	—	—	ns	XT osc mode (PIC16LV54A)	
			250	—	—	ns	HS osc mode (04)	
			100	—	—	ns	HS osc mode (10)	
			50	—	—	ns	HS osc mode (20)	
			5.0	_		μs	LP OSC mode	
		Oscillator Period <sup>(1)</sup>	250	_	_	ns	RC osc mode	
			500	—	—	ns	RC osc mode (PIC16LV54A)	
			250	—	10,000	ns	XT OSC mode	
			500	—	—	ns	XT osc mode (PIC16LV54A)	
			250	—	250	ns	HS osc mode (04)	
			100	—	250	ns	HS osc mode (10)	
			50	—	250	ns	HS osc mode (20)	
			5.0	_	200	μs	LP OSC mode	
2	Тсу	Instruction Cycle Time <sup>(2)</sup>	—	4/Fosc	—	—		
3	TosL, TosH	Clock in (OSC1) Low or	85*	_	—	ns	XT oscillator	
		High Time	20*	—	—	ns	HS oscillator	
			2.0*	—	—	μS	LP oscillator	
4	TosR, TosF	Clock in (OSC1) Rise or	—	_	25*	ns	XT oscillator	
		Fall Time	—	—	25*	ns	HS oscillator	
			—	—	50*	ns	LP oscillator	

\* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

**2:** Instruction cycle period (TcY) equals four times the input oscillator time base period.



#### **FIGURE 16-4:** TYPICAL RC OSCILLATOR FREQUENCY vs. VDD, CEXT = 300 PF, 25°C

# 17.0 ELECTRICAL CHARACTERISTICS - PIC16LC54A

# Absolute Maximum Ratings<sup>(†)</sup>

Ambient temperature under bias	–55°C to +125°C
Storage temperature	
Voltage on VDD with respect to Vss	0 to +7.5V
Voltage on MCLR with respect to Vss	0 to +14V
Voltage on all other pins with respect to Vss0.0	6V to (VDD + 0.6V)
Total power dissipation <sup>(1)</sup>	800 mW
Max. current out of Vss pin	150 mA
Max. current into Vod pin	
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, liк (Vi < 0 or Vi > VDD)	±20 mA
Output clamp current, IOK (VO < 0 or VO > VDD)	±20 mA
Max. output current sunk by any I/O pin	25 mA
Max. output current sourced by any I/O pin	20 mA
Max. output current sourced by a single I/O (Port A, B or C)	50 mA
Max. output current sunk by a single I/O (Port A, B or C)	50 mA
<b>Note 1:</b> Power dissipation is calculated as follows: Pdis = VDD x {IDD - $\sum$ IOH} + $\sum$ {(VDD-VOH) x let $x \in X$ }	OH} + $∑$ (VOL x IOL)

**†** NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

# 17.4 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

2. Tp	2. TppS							
Т								
F	Frequency	T Time						
Lowe	ercase letters (pp) and their meanings:							
рр								
2	to	mc MCLR						
ck	CLKOUT	osc oscillator						
су	cycle time	os OSC1						
drt	device reset timer	t0 T0CKI						
io	I/O port	wdt watchdog timer						
Uppe	ercase letters and their meanings:							
S								
F	Fall	P Period						
н	High	R Rise						
T	Invalid (Hi-impedance)	V Valid						
L	Low	Z Hi-impedance						

# FIGURE 17-5: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS -PIC16C54C/CR54C/C55A/C56A/CR56A/C57C/CR57C/C58B/CR58B-04, 20



# PIC16C5X

# FIGURE 18-10: VTH (INPUT THRESHOLD TRIP POINT VOLTAGE) OF OSC1 INPUT (IN XT, HS AND LP MODES) vs. VDD









### FIGURE 19-5: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16C5X-40

## TABLE 19-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16C5X-40

AC Characteristics		Standard Operating Conditions (unless otherwise specified)Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ (commercial)Operating Voltage VDD range is described in Section 19.1.					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
30	TmcL	MCLR Pulse Width (low)	1000*	_	_	ns	VDD = 5.0V
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
32	Tdrt	Device Reset Timer Period	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
34	Tioz	I/O Hi-impedance from MCLR Low	100*	300*	1000*	ns	

\* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

# APPENDIX A: COMPATIBILITY

To convert code written for PIC16CXX to PIC16C5X, the user should take the following steps:

- 1. Check any CALL, GOTO or instructions that modify the PC to determine if any program memory page select operations (PA2, PA1, PA0 bits) need to be made.
- 2. Revisit any computed jump operations (write to PC or add to PC, etc.) to make sure page bits are set properly under the new scheme.
- 3. Eliminate any special function register page switching. Redefine data variables to reallocate them.
- 4. Verify all writes to STATUS, OPTION, and FSR registers since these have changed.
- 5. Change RESET vector to proper value for processor used.
- 6. Remove any use of the ADDLW, RETURN and SUBLW instructions.
- 7. Rewrite any code segments that use interrupts.

# APPENDIX B: REVISION HISTORY

Revision KE (January 2013)

Added a note to each package outline drawing.

# PIC16C5X

## INDEX

## Α

Absolute Maximum Ratings
PIC16C54/55/56/5767
PIC16C54A103
PIC16C54C/CR54C/C55A/C56A/CR56A/C57C/CR57C/
C58B/CR58B 131
PIC16C54C/CR54C/C55A/C56A/CR56A/C57C/CR57C/
C58B/CR58B-40 155
PIC16CR54A79
ADDWF
ALU
ANDLW
ANDWF51
Applications5
Architectural Overview
Assembler
MPASM Assembler 61

# в

Block Diagram	
On-Chip Reset Circuit	
PIC16C5X Series	
Timer0	
TMR0/WDT Prescaler	41
Watchdog Timer	
Brown-Out Protection Circuit	
BSF	
BTFSC	
BTFSS	

# С

CALL	31, 53
Carry (C) bit	9, 29
Clocking Scheme	
CLRF	53
CLRW	53
CLRWDT	53
CMOS Technology	1
Code Protection	43, 47
COMF	54
Compatibility	
Configuration Bits	

# D

Data Memory Organization
PIC16C54/55/56/57
Commercial
Extended70, 72
Industrial69, 71
PIC16C54A
Commercial104, 109
Extended106, 109
Industrial 104, 109
PIC16C54C/C55A/C56A/C57C/C58B-40
Commercial157, 158
PIC16C54C/CR54C/C55A/C56A/CR56A/C57C/CR57C/
C58B/CR58B
Commercial134, 138
Extended137, 138
Industrial134, 138
PIC16CR54A
Commercial

Extended	82, 84
Industrial	80, 83
PIC16LV54A	
Commercial	108, 109
Industrial	108, 109
DECF	54
DECFSZ	54
Development Support	61
Device Characterization	
PIC16C54/55/56/57/CR54A	91
PIC16C54A	117
PIC16C54C/C55A/C56A/C57C/C58B-40	165
Device Reset Timer (DRT)	23
Device Varieties	7
Digit Carry (DC) bit	
DRT	23

# Ε

Electrical Specifications
PIC16C54/55/56/57 67
PIC16C54A103
PIC16C54C/CR54C/C55A/C56A/CR56A/C57C/CR57C/
C58B/CR58B 131
PIC16C54C/CR54C/C55A/C56A/CR56A/C57C/CR57C/
C58B/CR58B-40155
PIC16CR54A 79
Errata
External Power-On Reset Circuit 21

# F

Family of Devices	
PIC16C5X	
FSR Register	
Value on reset	

# G

General Purpose Registers	
Value on reset	20
GOTO 31	l, 55

# Н

High-Performance RISC CPU	. 1
---------------------------	-----

# ī

•	
I/O Interfacing	35
I/O Ports	35
I/O Programming Considerations	36
ICEPIC In-Circuit Emulator	62
ID Locations	43, 47
INCF	55
INCFSZ	55
INDF Register	33
Value on reset	20
Indirect Data Addressing	33
Instruction Cycle	13
Instruction Flow/Pipelining	13
Instruction Set Summary	49
IORLW	56
IORWF	56
к	

# KeeLoq Evaluation and Programming Tools ...... 64

3	1
3	1

L

NOTES:

# **PRODUCT IDENTIFICATION SYSTEM**

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	- <u>xx</u>	Ť	<u>/xx</u>	<u>xxx</u>	Exa	nples	S:	
Device	Frequency Range/OSC Type           PIC16C54           PIC16C54A           PIC16C54C           PIC16C55A           PIC16C55A           PIC16C55A           PIC16C56A           PIC16C57C           PIC16C57C           PIC16C58B           PIC16C58B	Temperature Range	(2) T(2)	Pattern	a) b) c) d) Note	PDIP QTP PIC10 packa PIC10 cial te dard PIC1 temp MHz, #123	<ol> <li>C = normal voltage range LC = extended</li> </ol>	
Frequency Range/ Oscillator Type	<ul> <li>RC Resistor Capacitor</li> <li>LP Low Power Crystal</li> <li>XT Standard Crystal/Resonator</li> <li>High Speed Crystal</li> <li>200 KHz (LP) or 2 MHz (XT and RC)</li> <li>400 KHz (LP) or 4 MHz (XT and RC)</li> <li>10 MHz (HS only)</li> <li>20 20 MHz (HS only)</li> <li>40 MHz (HS only)</li> <li>40 MHz (HS only)</li> <li>b<sup>(4)</sup> No oscillator type for JW packages<sup>(3)</sup></li> <li>*RC/LP/XT/HS are for 16C54/55/56/57 devices only</li> <li>-04/10/20 options are available for all other devices</li> <li>-40 is available for 16C54/C55A/56A/57C/58B devices only</li> </ul>					3:	T = in tape and reel - SOIC and SSOP packages only JW Devices are UV erasable and can be programmed to any device configura- tion. JW Devices meet the electrical requirements of each oscillator type, including LC devices. b = Blank	
Temperature Range	$b^{(4)} = 0^{\circ}C$ $I = -40^{\circ}C$ $E = -40^{\circ}C$	to +85°C						
Package	JW = 28-pin DIP <sup>(3)</sup> P = 28-pin SO = 300 m SS = 209 m SP = 28-pin	Waffle Pack 600 mil/18-pin 300 600 mil/18-pin 300 il SOIC il SSOP 300 mil Skinny PE for additional packa	) mil PDIP DIP					
Pattern		I code (factory spe lank for OTP and V						

#### Sales and Support

#### **Data Sheets**

Products supported by a preliminary Data Sheet may have an errata sheet describing minor operational differences and recommended workarounds. To determine if an errata sheet exists for a particular device, please contact one of the following:

1. Your local Microchip sales office

2. The Microchip Worldwide Site (www.microchip.com)